

MOSFETs Silicon N-channel MOS (U-MOSIV)

# TK80S04K3L

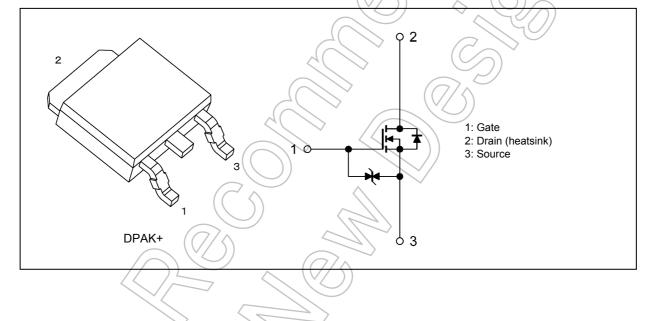
#### 1. Applications

- · Automotive
- · Motor Drivers
- DC-DC Converters
- · Switching Voltage Regulators

#### 2. Features

- (1) AEC-Q101 qualified
- (2) Low drain-source on-resistance:  $R_{DS(ON)} = 2.4 \text{ m}\Omega$  (typ.) ( $V_{GS} = 10 \text{ V}$ )
- (3) Low leakage current:  $I_{DSS}$  = 10  $\mu A$  (max) ( $V_{DS}$  = 40 V)
- (4) Enhancement mode:  $V_{th} = 2.0 \text{ to } 3.0 \text{ V } (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

#### 3. Packaging and Internal Circuit



Start of commercial production



### 4. Absolute Maximum Ratings (Note) (Ta = 25°C unless otherwise specified)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	40	V
Gate-source voltage		V <sub>GSS</sub>	±20	
Drain current (DC)	(Note 1)	I <sub>D</sub>	80	Α
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	160	
Power dissipation (T <sub>c</sub> = 2	25°C)	$P_{D}$	100	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	135	mJ
Avalanche current		IAR	80	Α
Channel temperature	(Note 3)	T <sub>ch</sub>	)) 175	ç
Storage temperature	(Note 3)	T <sub>stg</sub>	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### 5. Thermal Characteristics

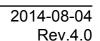
	Characteristics		Symbol	Max	Unit
Channel-to-case thermal resistance			R <sub>th(ch-c)</sub>	1.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 175°C.

Note 2:  $V_{DD}$  = 25 V,  $T_{ch}$  = 25°C (initial), L = 22  $\mu$ H,  $R_G$  = 1  $\Omega$ ,  $I_{AR}$  = 80 A

Note 3: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.





#### 6. Electrical Characteristics

## 6.1. Static Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V	7	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	40	_	_	V
	V <sub>(BR)DSX</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -20 V	20	) ~		
Gate threshold voltage	$V_{th}$	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0	/_	3.0	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 6 V, I <sub>D</sub> = 40 A	/	3.0	4.8	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 40 A	)	2.4	3.1	

## 6.2. Dynamic Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	- /	4340		pF
Reverse transfer capacitance	C <sub>rss</sub>	((// \) \ \	_((	570	\	
Output capacitance	C <sub>oss</sub>		K	910	) —	
Switching time (rise time)	t <sub>r</sub>	See Figure 6.2.1.		13		ns
Switching time (turn-on time)	t <sub>on</sub>			28	_	
Switching time (fall time)	t <sub>f</sub>		//-//	20		
Switching time (turn-off time)	t <sub>off</sub>			80	_	

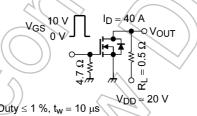


Fig. 6.2.1 Switching Time Test Circuit

## 6.3. Gate Charge Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 32 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 80 \text{ A}$	_	87	_	nC
Gate-source charge	Q <sub>gs</sub>		_	57	_	
Gate-drain charge	$Q_{gd}$		_	30	_	

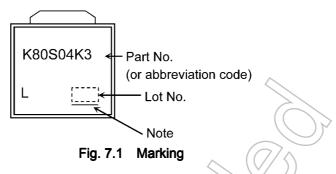
## 6.4. Source-Drain Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 4)	I <sub>DR</sub>	_			80	Α
Reverse drain current (pulsed)	(Note 4)	I <sub>DRP</sub>	_	_	_	160	
Diode forward voltage		$V_{DSF}$	I <sub>DR</sub> = 80 A, V <sub>GS</sub> = 0 V	_	_	-1.2	V
Reverse recovery time		t <sub>rr</sub>	I <sub>DR</sub> = 80 A, V <sub>GS</sub> = 0 V	_	57	_	ns
Reverse recovery charge		Q <sub>rr</sub>	-dI <sub>DR</sub> /dt = 50 A/μs	_	45		nC

Note 4: Ensure that the channel temperature does not exceed 175°C.



## 7. Marking (Note)



Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

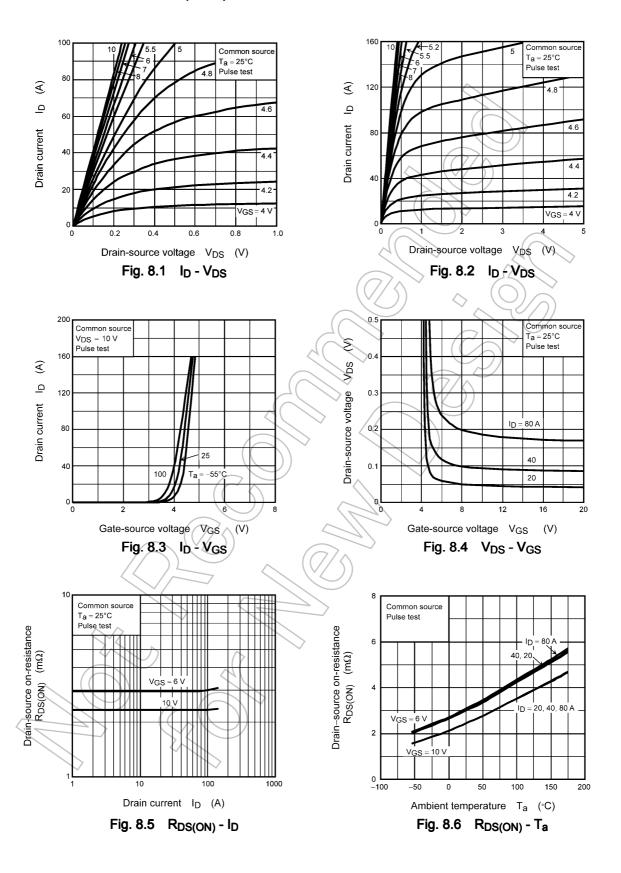
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.



### 8. Characteristics Curves (Note)



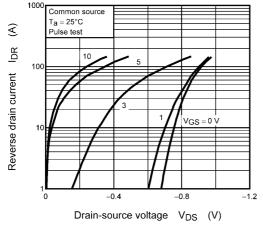


Fig. 8.7  $I_{DR}$  -  $V_{DS}$ 

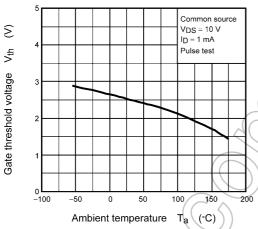
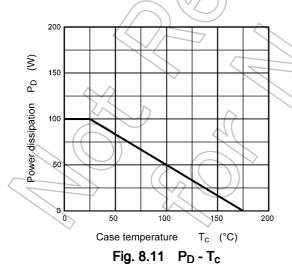


Fig. 8.9 V<sub>th</sub> - T<sub>a</sub>



(Guaranteed Maximum)

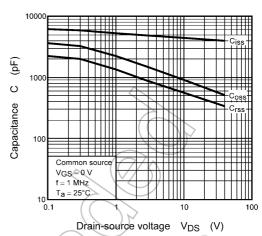


Fig. 8.8 Capacitance - V<sub>DS</sub>

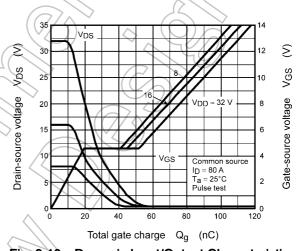
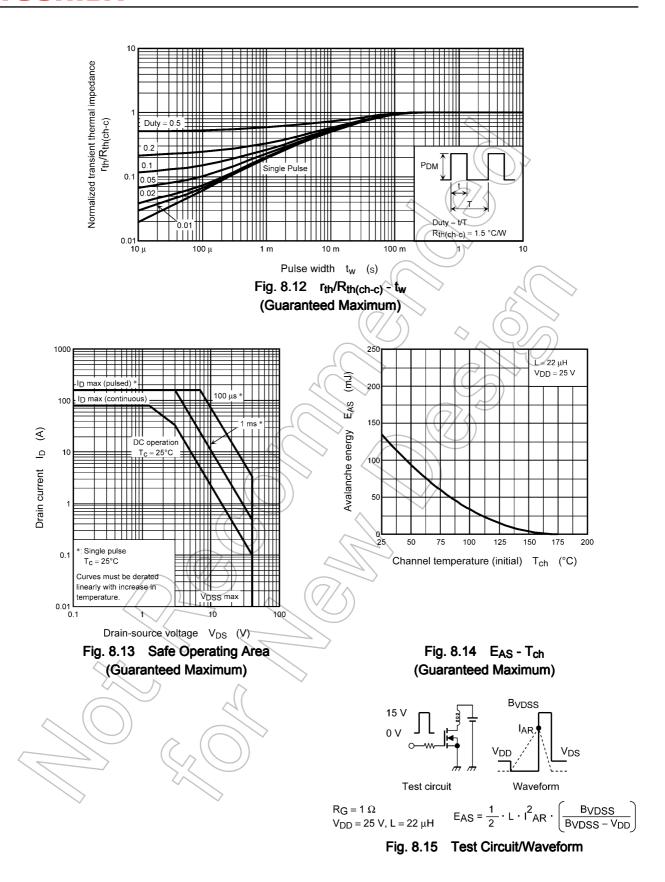


Fig. 8.10 Dynamic Input/Output Characteristics

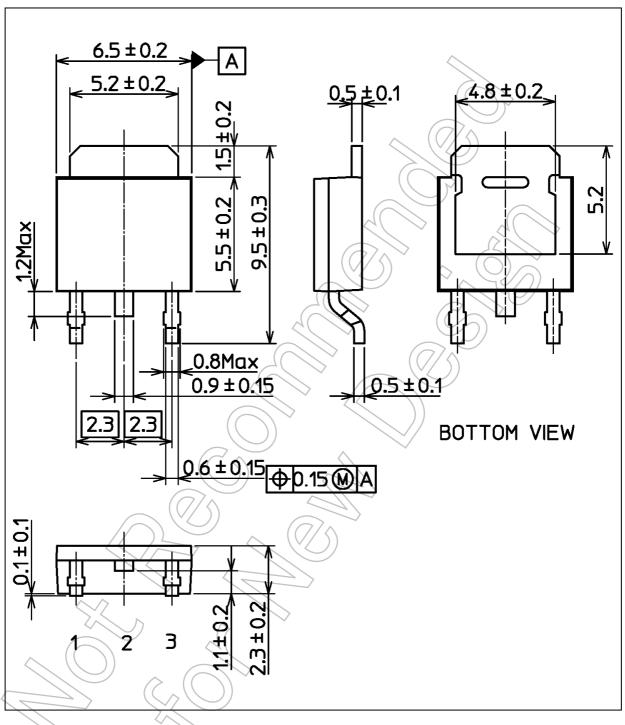


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## **Package Dimensions**

Unit: mm



Weight: 0.36 g (typ.)

	Package Name(s)
TOSHIBA: 2-7M1A	
Nickname: DPAK+	



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